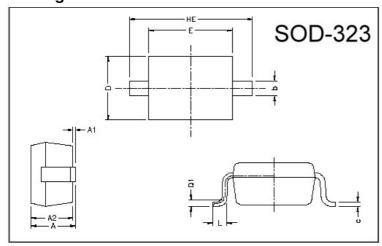
# GDMBD2004

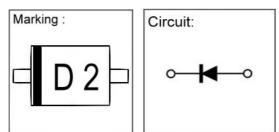
## SURFACE MOUNT, SWITCHING DIODE **VOLTAGE 300V, CURRENT 0.225A**

### **Description**

The GDMBD2004 is designed for ultra high speed switching.

## **Package Dimensions**





REF.	Millimeter		REF.	Millimeter	
	Min.	Max.	NEF.	Min.	Max.
Α	0.85	1.05			
A1	0	0.10	L	0.20	0.40
A2	0.80	1.00	b	0.25	0.40
D	1.15	1.45	С	0.10	0.18
Е	1.60	1.80			
HE	2.30	2.70	Q1	0.15 BSC.	

#### **Absolute Maximum Ratings** (At TA = 25°C unless otherwise specified)

Parameter	Symbol Ratings		Unit	
Repetitive Peak Reverse Voltage	VRRM	300	V	
Continuous reverse voltage	VR(VRWM)	240	V	
RMS Reverse Voltage	VR(RMS)	170	V	
Forward Continuous Current	lғм	225	mA	
Non-Repetitive Peak Forward surge Current @Tp =1.0us	Ifsm -	4	Α	
@Tp=1.0s		1		
Typical Junction Capacitance between Terminal (Note1)	Сл	5.0	pF	
Max. Reverse Recovery Time (Note2)	TRR	50	nSec	
Power Dissipation	PD	350	mW	
Thermal Resistance Junction to Ambient Air	Reja	357	°C/W	
Operation and Storage Temperature Range	TJ, TSTG	-65 ~ +150	$^{\circ}\! \mathbb{C}$	

### Electrical Characteristics (At TA = 25°C unless otherwise noted)

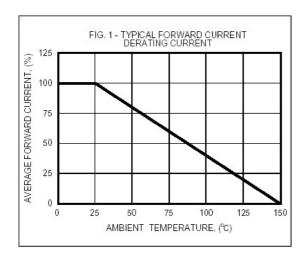
Characteristics	Symbol	Min.	Max.	Unit	Test Conditions				
Reverse Breakdown Voltage	BVR	300	-	V	IR=100uA				
			0.85	V	IF=20mA				
Forward Voltage	VF	-	1	V	IF=100mA				
		-	1.25	V	IF=225mA				
Reverse Current	lr	-	100	nA	VR=240V, Ta=25°C				
neverse Guitein			100	uA	VR=240V, Ta=150°C				

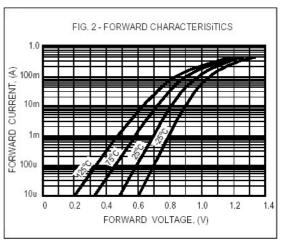
Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 0 volts.

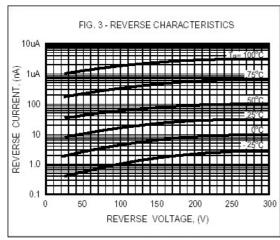
- 2. Measured at applied forward current of 30mA, reverse current of 30mA,  $R_L$ =100 $\Omega$  and recovery to  $I_{RR}$ =-3mA.
- 3. ESD sensitive product handling required.

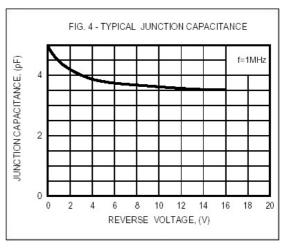
GDMBD2004 Page: 1/2

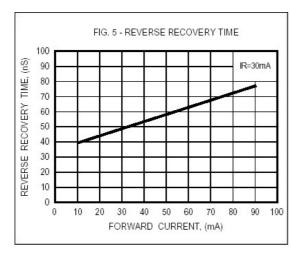
#### **Characteristics Curve**

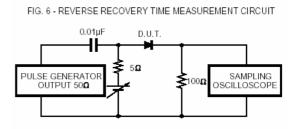












#### Important Notice:

- All rights are reserved. Reproduction in whole or in part is prohibited without the prior written approval of GTM.
- GTM reserves the right to make changes to its products without notice.

  GTM semiconductor products are not warranted to be suitable for use in life-support Applications, or systems.

  GTM assumes no liability for any consequence of customer product design, infringement of patents, or application assistance.

- GTM assorties to liability for any consequence of customer product design, miningement of patents, read Office And Factory:

  Taiwan: No. 17-1 Tatung Rd. Fu Kou Hsin-Chu Industrial Park, Hsin-Chu, Taiwan, R. O. C.
  TEL: 886-3-597-7061 FAX: 886-3-597-9220, 597-0785
  China: (201203) No.255, Jang-Jiang Tsai-Lueng RD. , Pu-Dung-Hsin District, Shang-Hai City, China
  TEL: 86-21-5895-7671 ~ 4 FAX: 86-21-38950165

GDMBD2004 Page: 2/2